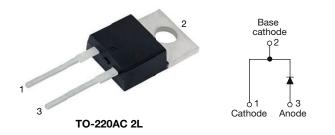
Vishay Semiconductors

ROHS COMPLIANT

HALOGEN

FREE

High Voltage, Input Rectifier Diode, 10 A



www.vishay.com

PRIMARY CHARACTERISTICS		
I _{F(AV)} 10 A		
V _R	800 V to 1200 V	
V _F at I _F	1.1 V	
I _{FSM}	160 A	
T _J max.	150 °C	
Package	TO-220AC 2L	
Circuit configuration	Single	

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- Glass passivated pellet chip junction
- \bullet Designed and qualified according to JEDEC $^{\textcircled{B}}\text{-}JESD$ 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	CATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS			
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	12.0	16.0	A	

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Sinusoidal waveform	10	A	
V _{RRM}		800/1200	V	
I _{FSM}		160	A	
V _F	10 A, T _J = 25 °C	1.1	V	
TJ		-40 to +150	°C	

VOLTAGE RATINGS				
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA	
VS-10ETS08-M3	800 900		0.5	
VS-10ETS12-M3	1200	1300	0.5	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	OL TEST CONDITIONS VALUES		UNITS	
Maximum average forward current	I _{F(AV)}	$T_C = 105$ °C, 180° conduction half sine wave	10		
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	135	А	
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	160		
Maximum I ² t for fusing I ² t		10 ms sine pulse, rated V _{RRM} applied	91	A ² s	
		10 ms sine pulse, no voltage reapplied	130	A-S	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1300	A²√s	

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VS-10ETS...-M3 Series



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	T_{M} 10 A, T_{J} = 25 °C		1.1	V
Forward slope resistance	r _t	T₁ = 150 °C		20	mΩ
Threshold voltage	V _{F(TO)}	IJ = 150 C		0.82	V
Maximum reverse leakage current	less.	T _J = 25 °C	$V_{B} = Rated V_{BBM}$	0.05	mA
Maximum reverse leakage current	IRM	T _J = 150 °C	VR - Haleu VRRM	0.50	ШA

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	
Maximum thermal resistance, junction to ambient (PCB mount)	R _{thJA}		62	°C/W
Soldering temperature	Τ _S		240	°C
Approximate weight			2	g
Approximate weight			0.07	oz.
Marking device			10ET	S08
		Case style TO-220AC 2L	10ET	S12

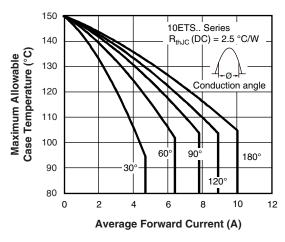


Fig. 1 - Current Rating Characteristics

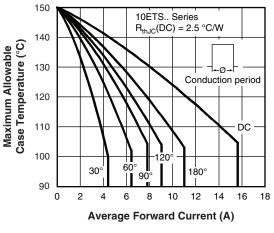


Fig. 2 - Current Rating Characteristics

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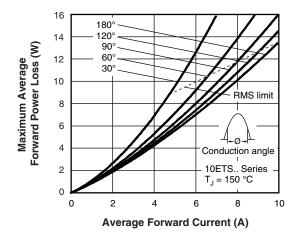


Fig. 3 - Forward Power Loss Characteristics

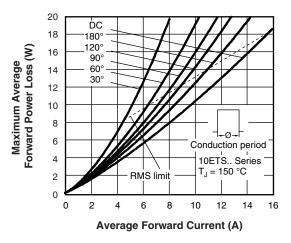
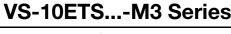
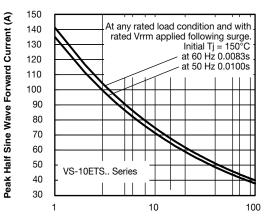


Fig. 4 - Forward Power Loss Characteristics



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Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

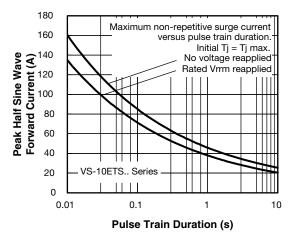


Fig. 6 - Maximum Non-Repetitive Surge Current

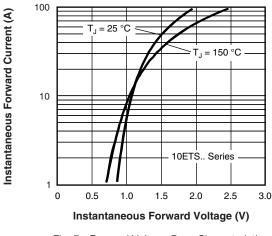


Fig. 7 - Forward Voltage Drop Characteristics

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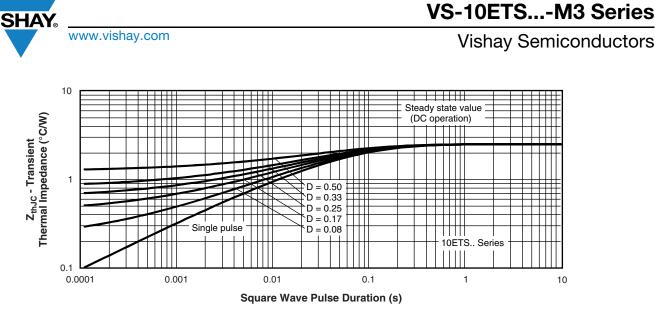


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

ORDERING INFORMATION (Example)				
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-10ETS08-M3	50	Antistatic plastic tubes		
VS-10ETS12-M3	50	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?96156			
Part marking information	www.vishay.com/doc?95391		

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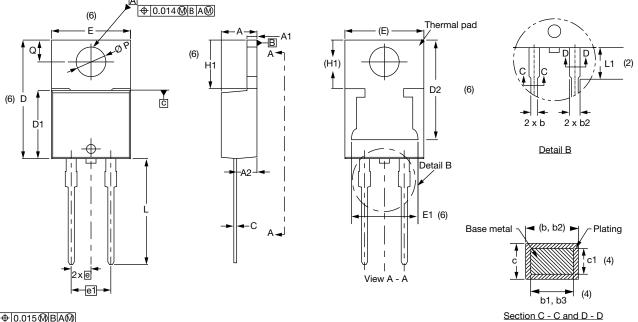
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Vishay Semiconductors

TO-220AC 2L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIMETERS		INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC	® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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